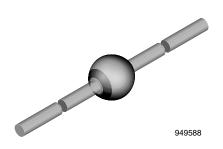


Vishay Semiconductors

Standard Avalanche Sinterglass Diode



FEATURES

- · Glass passivated junction
- Hermetically sealed package



Halogen-free according to IEC 61249-2-21 definition



RoHS

HALOGEN FREE

APPLICATIONS

- High voltage rectification
- Efficiency diode in horizontal deflection circuit

MECHANICAL DATA

Case: SOD-64

Terminals: plated axial leads, solderable per MIL-STD-750,

method 2026

Polarity: color band denotes cathode end

Mounting position: any **Weight:** approx. 858 mg

PARTS TABLE		
PART	TYPE DIFFERENTIATION	PACKAGE
BY228	V _R = 1500 V; I _{FAV} = 3 A	SOD-64

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
Reverse voltage	See electrical characteristics	V _R	1500	V	
Repetitive peak reverse voltage	I _R = 100 μA	V _{RRM}	1650	V	
Peak forward surge current	t _p = 10 ms, half sine wave	I _{FSM}	50	Α	
Average forward current		I _{FAV}	3	А	
Junction temperature		T _j	140	°C	
Storage temperature range		T _{stg}	- 55 to + 175	°C	
Non repetitive reverse avalanche energy	$I_{(BR)R} = 0.4 \text{ A}$	E _R	10	mJ	

MAXIMUM THERMAL RESISTANCE (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Junction ambient	On PC board with spacing 25 mm	R _{thJA}	70	K/W	

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX	UNIT
Forward voltage	I _F = 5 A	V _F	-	-	1.5	V
Reverse current	V _R = 1500 V	I _R	-	2	5	μA
	$V_R = 1500 \text{ V}, T_j = 140 ^{\circ}\text{C}$	I _R	-	-	140	μA
Total reverse recovery time	$I_F = 1 A$, - $dI_F/dt = 0.05 A/\mu s$	t _{rr}	-	-	20	μs
Reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_R = 0.25 \text{ A}$	t _{rr}	-	-	2	μs

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TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

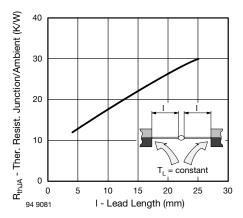


Fig. 1 - Typ. Thermal Resistance vs. Lead Length

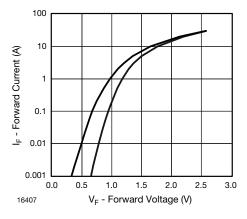


Fig. 2 - Forward Current vs. Forward Voltage

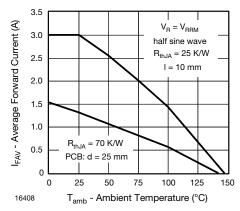


Fig. 3 - Max. Average Forward Current vs. Ambient Temperature

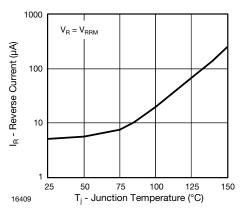


Fig. 4 - Reverse Current vs. Junction Temperature

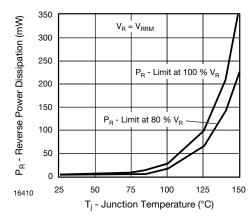


Fig. 5 - Max. Reverse Power Dissipation vs. Junction Temperature

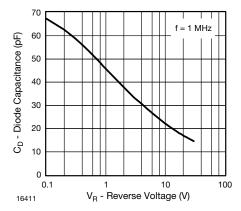


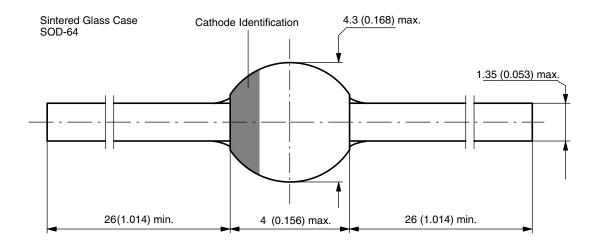
Fig. 6 - Diode Capacitance vs. Reverse Voltage



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PACKAGE DIMENSIONS in millimeters (inches): SOD-64



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